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# Inclosure Material:

Metal

**Overall Length:** 

1.573 inches

# **Overall Height:**

0.380 inches

# **Overall Width:**

1.050 inches

# **Mounting Facility Quantity:**

2

### Internal Configuration:

### Field effect

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

## **Mounting Method:**

Unthreaded hole

# Features Provided:

Hermetically sealed case and quality assurance level s

## Semiconductor Material:

### Silicon

# Voltage Rating In Volts Per Characteristic:

200.0 drain to gate voltage and 200.0 drain to source voltage

# **Current Rating Per Characteristic:**

9.00 amperes drain current and 9.00 amperes source current and 15.00 amperes off-state current, peak

# **Power Rating Per Characteristic:**

75.0 watts total power dissipation

# Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius ambient air

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Terminal Type And Quantity:**

2 pin and 1 case

### **Specification Data:**

81349-mil-s-19500/542 government specification

### Shelf Life:

N/a

Unit Of Measure:

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## Demilitarization:

No

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